NSN 5961-01-360-7469

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-360-7469 **Inclosure Material:** Glass **Overall Length:** Between 0.150 inches and 0.300 inches **Terminal Length:** Between 0.900 inches and 1.300 inches **Overall Diameter:** Between 0.115 inches and 0.140 inches **Function For Which Designed:** Transient suppressor **Mounting Method: Terminal Features Provided:** Quality assurance level txv **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 5.6 breakdown voltage, dc **Current Rating Per Characteristic:** 80.00 amperes forward current, average preset **Power Rating Per Characteristic:** 2.5 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No Fiig: A110a0